L Number	Hits	Search Text	DB	Time stamp
1	9	(pixel near10 (contact adj hole)) near10 (drain and gate and reflect$4)and (liquid adj crystal)	USPAT; US-PGPUB; JPO	2004/03/18 10:44
2	9	(pixel near10 (contact adj hole)) near10 (drain and gate and reflect$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:19
3	13	(pixel with (drain and gate and reflect$4)) near10 (contact adj hole$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:41
4	44	(pixel and (drain and gate and reflect$4)) near10 (contact adj hole$4)	USPAT; US-PGPUB; JPO	2004/03/18 11:41
-	1199	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 16:59
-	1340	349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:00
-	1346	349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:00
-	239	349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05
-	100	349/159	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05
-	168	349/162	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:05
-	233	345/80	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:06
-	805	345/90	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:07
-	3682313	(line or LOG)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:09
-	95863	(line or LOG)and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:10
-	59030	(line or LOG)and (liquid adj crystal) and driv$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:10

-	0	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and (AlNd adj alloy)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:12
-	85	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:12
-	50	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo) and Cr	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:13
-	78	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:16
-	2	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:18
-	1	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113 and 349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:18
-	1120	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113 or transflect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:19
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113 and transflect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:19
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/159	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:20
-	2	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/162	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/32	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/80	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 345/90	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21
-	525	345/32	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:21

-	7	(line or LOG) and (line with resistance) and (drive$4 with retard$4) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 17:26
-	99	349/113 and 349/114	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 17:27
-	252	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 18:00
-	183	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and insulat$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 18:03
-	38	(line or LOG)and (liquid adj crystal) and driv$4 and (double-layer) and insulat$ and (line with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/12 18:03
-	24	349/113 and 349/114 and (Cr or chromium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 17:29
-	8	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 18:03
-	0	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and ((gate adj line)and (data adj line) and (reflective adj electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 18:18
-	107	(line or LOG)and ((gate adj line)and (data adj line) and (reflective adj electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:33
-	35562	(choo or chung).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:34
-	7174	(choo or chung).in.	USPAT	2003/08/14 14:34
-	216	(choo or chung).in. and (liquid adj crystal)	USPAT	2003/08/14 14:35
-	5	(choo or chung).in. and (liquid adj crystal) and transflect$4 and reflect$4	USPAT	2003/08/14 15:22
-	1	6466280.pn.	USPAT	2003/08/14 15:22
-	18	(line or LOG)and driv$4 and (double-layer) and ((AlNd adj alloy) or Mo or molybdenum)and (Cr or chromium) and 349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 15:25